# ELECTRICAL CHARACTERISTICS OF ALUMINIUM DOPED NANOSTRUCTURED ${\rm TiO_2}$ THIN FILM BY SOL-GEL METHOD SPIN COATING

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## **ABSTRACT**

The study have been conducted on Electrical Characteristics of Aluminum Doped Nanostructured TiO<sub>2</sub> Thin Film. In this research, it have been prepared by a method known as Sol-gel method. Titanium dioxide (TiO2) thin films have been deposited on glass substrates using titanium Butoxide as a precursor. This research have been investigated on the different concentration of Aluminium doped Nanostructured Titanium Dioxide (TiO<sub>2</sub>) thin film from 1% to 5% by (molar percentage). The results in terms of electrical characteristics of the Aluminium doped Nanostructured TiO<sub>2</sub> thin film layer have been studied. When the concentration of doping Aluminium increased, the conductivity were increased and the resistivity were decreased. This is because Aluminium is one of the agent of conductivity. The spectral absorbance of undoped TiO<sub>2</sub> and Al doped TiO<sub>2</sub> thin films deposited on glass were measured in the wavelength range from 300 to 800 nm. The value of absorbance were increase rapidly within wavelength of 300 nm and 350 nm. The influences of different concentration of aluminium on the surface morphologies and electrical characteristics of the nanostructured TiO<sub>2</sub> were characterized by Scanning Electron Microscopy (SEM) and Current-Voltage (I-V) measurement. The optical properties of different concentration of aluminium of the nanostructured TiO<sub>2</sub> were characterized by UV-VIS Spectroscopy as well.

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## **CHAPTER 1**

## INTRODUCTION

#### 1.1 INTRODUCTION

Aluminium is a silvery white and ductile member of the boron group of chemical elements. It has the symbol Al and its atomic number is 13. It is not soluble in water under normal circumstances. Aluminium is the most abundant metal in the Earth's crust, and the third most abundant element therein after oxygen and silicon. It makes up about 8% by weight of the Earth's solid surface. Aluminium is too reactive chemically to occur in nature as a free metal.

Aluminium is a soft, durable, lightweight, malleable metal with appearance ranging from silvery to dull grey, depending on the surface roughness. Aluminium is nonmagnetic and nonsparking. It is also insoluble in alcohol, though it can be soluble in water in certain forms. Corrosion resistance can be excellent due to a thin surface layer of aluminium oxide that forms when the metal is exposed to air, effectively preventing further oxidation. The strongest aluminium alloys are less corrosion resistant due to galvanic reactions with alloyed copper. Aluminum doped Titanium Dioxide (TiO<sub>2</sub>) coatings exhibit high transparency and low resistivity and these materials are suitable for fabricating transparent electrodes in solar cells, gas sensors and ultrasonic oscillators.